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## **The Design and Simulation of a Planar Microarray Dot Electrode for a Dielectrophoretic Lab-on-Chip Device**

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Dielectrophoresis (DEP) has been proven as a method of manipulating and analyzing the electrophysiological properties of bioparticles by applying non-uniform electric fields generated through special electrodes. Various electrode geometries have been developed to address different applications. Electric field simulation over electrodes is essential in order to optimize the generated DEP force for cell manipulation. This paper describes the study of electric field distribution over planar multiple microarray dot electrodes using numerical modeling of Comsol Multiphysics 4.2a<sup>®</sup>. Electric field evaluation for different dot sizes has been demonstrated by applying a range of frequencies to the designed electrodes. Results show that the electric field is axisymmetrical around the center of the dot aperture and that it is higher at the dot edges than the dot centers. Furthermore, adding ground plane between adjacent dots increases the electric field strength.

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**Keywords:** Dielectrophoresis; Numerical modeling; Dot microarray electrodes

### **1. INTRODUCTION**

Microfluidic devices have the potential to be used for early detection and diagnosis of disease at Point-of-Care (POC). This is aligned with the current trend of miniaturizing laboratory equipment to achieve better reactions efficiency, faster results, portability and lower reagents consumption. One of the platforms used in microfluidic devices is Lab-on-chip, which is a potential solution for an automated bio-microfluidic diagnostic system that requires the minimum quantity of blood and offers fast and high-throughput results.

Many diagnostic techniques have been employed using lab-on-chip platforms; however, dielectrophoresis (DEP) has been proven to offer a number of advantageous features that many of the other techniques available are unable to provide. These include high selectivity and efficacy, non-

invasiveness and low cost. DEP has been used as a method for cell manipulation and characterization since its discoverer Pohl [1] launched a novel technique for separating living cells from admixed dead ones, taking advantage of the unique electrical properties of each bioparticles [2]. DEP is the phenomenon that describes the motion of polarizable particles through a non-uniform electric field. One of the core strengths of DEP is that the characterization of different cells depends only on the dielectric properties controlled by the particle's individual phenotype. Hence, the process does not require specific tags or involve chemical reactions [3].

The DEP force depends on the applied frequency and geometry of the electrodes used to generate the electric field. Different electrode geometries have been used in previous studies for different applications. This study provides a numerical analysis of the electric field generated by a 4x4 planar multiple microarray dot electrode, which is a modification of that used by Fatoyinbo *et al.* [4]. The adjustment geometry parameters for the electrode were employed to produce the optimum design. In order to optimize the size of the dots, the designed electrodes were numerically analyzed and their electric field strength and distribution were compared for different dot diameters. The dots diameter was adjusted by changing either the ring width or the distance between the adjacent dots. Moreover, the effect of adding ground plane between dot apertures was evaluated. These electrodes will be used to conduct DEP experiments as a sample preparation prior to the stage of infectious diseases diagnosis.

### 1.1. Dielectrophoretic theory

Applying a non-uniform electric field to polarizable particles that are placed in a conductive medium produces DEP force. The magnitude and direction of the DEP force depends on the relative polarizability of the particle and the surrounding medium [5]. The DEP force acting on a spherical particle can be expressed by the following equation [6]:

$$\langle \vec{F}_{DEP} \rangle = 2\pi r^3 \varepsilon_o \varepsilon_m \operatorname{Re}[K(\omega)] \nabla E^2 \quad (1)$$

where  $\varepsilon_o$  is the permittivity of free space,  $\varepsilon_m$  is the permittivity of the surrounding medium,  $r$  is the particle radius,  $\nabla E$  is the electric field gradient and  $\operatorname{Re}[K(\omega)]$  is the real part of Clausius-Mossotti factor, which is defined as:

$$K(\omega) = \frac{\varepsilon_p^* - \varepsilon_m^*}{\varepsilon_p^* + 2\varepsilon_m^*} \quad (2)$$

where  $\varepsilon^*$  is the complex permittivity and subscripts  $p$  and  $m$  denote particles and medium respectively. Moreover, the complex permittivity  $\varepsilon^*$  is described by:

$$\varepsilon^* = \varepsilon - j \frac{\sigma}{\omega} \quad (3)$$

where  $\varepsilon$  is the permittivity,  $j = \sqrt{-1}$ ,  $\sigma$  is the conductivity and  $\omega$  is the angular frequency of the applied AC electric field. The value of  $Re[K(\omega)]$  for a sphere ranges between -0.5 and 1, and depends on the frequency of the applied AC electric field and relative polarizability between the particle and its surrounding medium [6]. When  $Re[K(\omega)] > 0$ , the particles undergo positive DEP and move toward the high electric field gradient region. However, when  $Re[K(\omega)] < 0$ , the particles travel to the low electric field gradient region as a result of the negative DEP effect.

## 1.2. Electrode design

In order to minimize the value of the applied voltage, the non-uniform electric field required for DEP is typically produced by electrodes on the scale of microns. Electrode geometries can be categorized into two main groups: planar and 3D electrodes. Planar electrodes are typically patterned on the bottom of the microchannel using conventional lithography techniques. Examples of planar electrode designs include interdigitated [7], castellated [8], spiral [9], curved [10], oblique [11], quadrupole [12], matrix [4] and polynomial [13]. On the other hand, 3D electrodes are designed on the bottom, bottom/top, or side wall of the microchannel using complicated techniques. Examples of 3D electrode designs are grid [14], microwells [15], DEP-well [16], extruded [17], sidewall patterned [18] and top-bottom patterned [19]. This variety of electrode geometry has evolved in response to the need to address different research tasks. Hence, the electrode geometry that is used is determined by the general goal of the study.

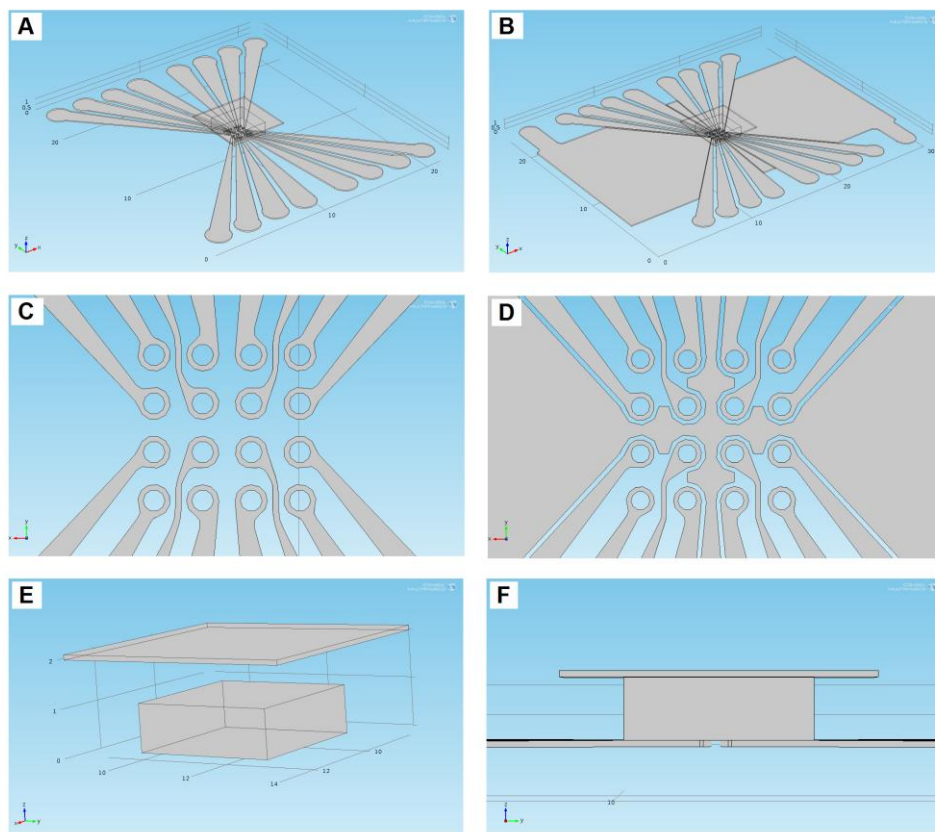
A planar multiple microarray dot electrode was chosen in this study because it has a well-defined and enclosed region of analysis. This type of electrode has been proven to create electric fields with axisymmetrical gradient around every dot aperture [20]. The current 4x4 microarray dot electrode was designed in this study in such a way that individual dots can be electrically supplied independently, giving the capability to observe and record cellular electrophysiological changes in near real-time by conducting multiple DEP experiments in parallel.

## 2. METHODOLOGY

AC/DC module of Comsol Multiphysics 4.2a<sup>®</sup> (COMSOL Inc, Palo Alto, USA) was used to model the electric field distribution over the microarray dot electrodes. A few assumptions were made to mimic the actual situation and to provide greater processing memory and a better fitting mesh of the model. Two main 3D models were designed in order to perform the objective of the study. These are shown in Fig. 1.

The designed 3D model represents a gasket chamber sandwiched between a bottom patterned electrode and a top “ground” electrode, as shown in Fig 1(A), with a total electrode size of 22 x 22 mm<sup>2</sup>. Adding ground plane between dots apertures lead to the second design, which is shown in Fig. 1(B). Furthermore, Fig. 1(C) and (D) illustrate the bottom patterned electrodes without and with ground plane respectively, with a thickness of 0.1 mm. The top ground electrode was modeled as a

5x5x0.1 mm<sup>3</sup> solid block, while the gasket chamber was represented by 3x3x1 mm<sup>3</sup> solid block, as depicted in Fig. 1(E) and (F).



**Figure 1.** Two designs of the planar multiple microarray dot electrode: (A) the full design for electrodes without ground plane between dots apertures. (B) the design with ground plane between dots apertures. The pattern of the 4x4 microarray dot electrode without ground plane (C) and with ground plane (D). (E) three dimensional view of the ground electrode and the gasket chamber, while (F) is a front view of the entire design.

In order to optimize the size of the dots, dots were given diameters of 100, 150, and 200  $\mu\text{m}$  for both electrode designs. The diameter of the dots was adjusted by changing either the ring width or the distance between adjacent dots. First, the size of the dots was modified by varying the ring width 100, 75 and 50  $\mu\text{m}$ , for the diameters of 100, 150, and 200  $\mu\text{m}$  respectively. The distances between adjacent dots and between the center of the dots were fixed at 150 and 450  $\mu\text{m}$  respectively. Second, in order to investigate whether the ring width variation has an effect on the electric field strength, other simulations were conducted such that the width of the rings was fixed at 50  $\mu\text{m}$  for all sizes of the dots, while varying the distances between adjacent dots (distance between dots centers remained fixed at 450  $\mu\text{m}$ ).

The patterned dot electrode and ground plane between the aperture of the dots were given gold properties  $\sigma = 4.1 \times 10^7 \text{ S/m}$  and  $\epsilon_r = 1$ , the ground top electrode was given material properties of indium tin oxide (ITO)  $\sigma = 1.3 \times 10^4 \text{ S/m}$  and  $\epsilon_r = 10$ . Finally, the gasket chamber, which represents the

suspending medium, was given the material properties of deionized water  $\sigma = 2 \times 10^{-4}$  S/m and  $\epsilon_r = 78$  [20, 21].

The entire geometries were meshed using tetrahedral elements with maximum and minimum element sizes of 5 and 0.05 mm respectively. Boundary conditions for the top electrode and ground plane between the apertures of the dots were defined as ground, while the patterned electrode was supplied with 10 Vp.

A range of frequencies was applied to observe any changes in the generated electric field strength and distribution over the designed electrodes. The applied frequencies were 100 Hz, 1 kHz, 10 kHz, 50 kHz, 100 kHz, 500 kHz, 1 MHz and 2 MHz.

### 3. RESULTS AND DISCUSSION

Different experiments were conducted utilizing different frequencies; however, the change in the electric field strength (V/m) and distribution was negligible. Frequency plays a significant role in determination of the Clausius-Mosotti factor  $[K(\omega)]$ , which affects the DEP force, as expressed in equation (1) [6]. Therefore, frequency controls the DEP force via Clausius-Mosotti factor rather than electric field strength.

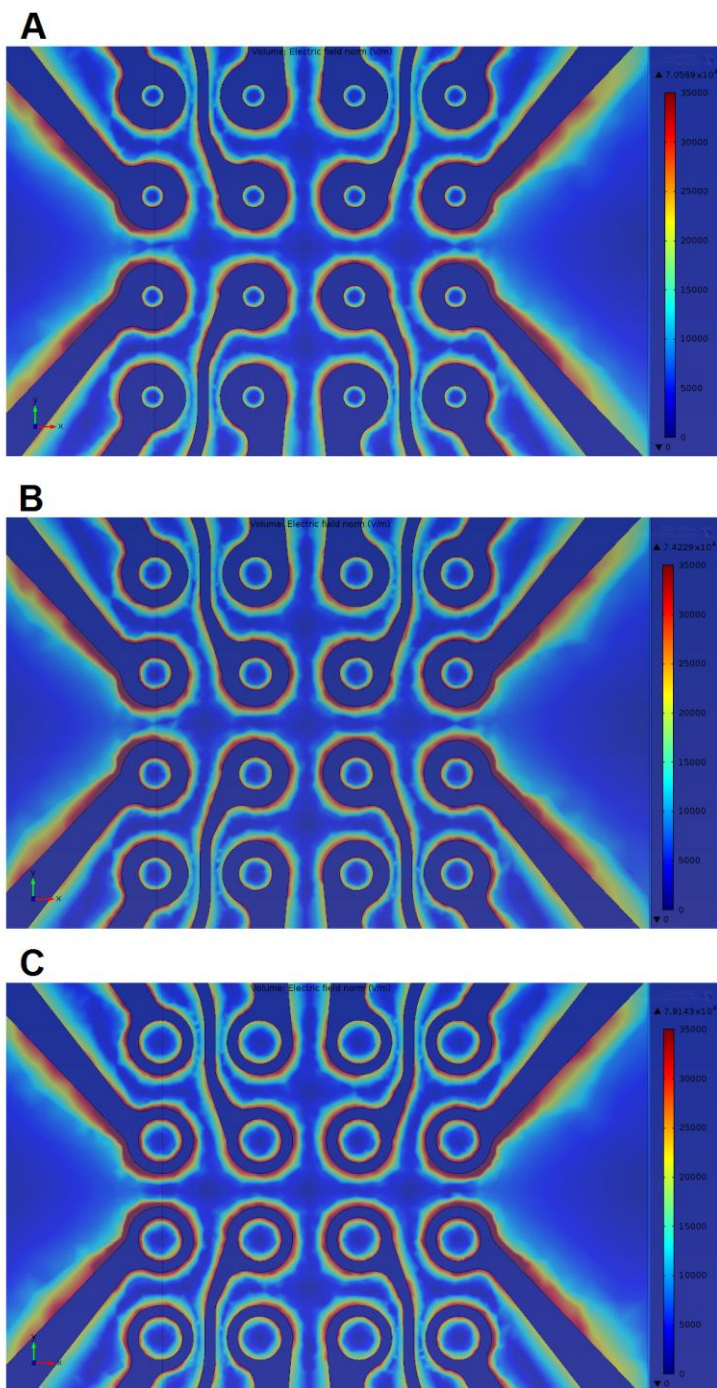
The rest of the experiments were simulated by applying 100 kHz. Fig. 2 shows the distribution of the strength of the electric field of the electrodes without ground plane between the apertures of the dots, with dot diameters 100, 150 and 200  $\mu\text{m}$ . On the other hand, Fig. 3 illustrates the distribution of the electric field strengths of electrodes with ground plane between the apertures of the dots, with dot diameters of 100, 150 and 200  $\mu\text{m}$ . These results are associated with the adjustment of ring width to change the diameters of the dots. The strength of the electric field is illustrated by color ranging from blue (least strength) to red (most strength).

The results revealed that the values of the electric field strength at the edge of the dots are higher than that at the center of the dots for all electrode designs. This is aligned with the previous simulations in the literature that show the electric field of a planar electrodes increases near the electrode edge [6, 22-24]. Therefore, the DEP force is expected to be higher at the dot edges rather than at the dot centers, which is in agreement with the earlier works of Fatoyinbo et al. [4, 20].

Moreover, Fig. 2 and 3 depicts that the electric field strengths are axisymmetrical around the center of the aperture of the dots, which suggests that the DEP force is also axisymmetrical within the dot volume. This indicates that the particles will undergo homogenous radial movement. The direction of this movement will depend on Clausius-Mosotti factor. If it is positive, particles will be attracted to the dot edges. However, if Clausius-Mosotti factor is negative, particles will be repelled to the centers of the dots. This finding is in consistent with the work done by Kadri et al., in which K562 leukemic cells were collected at the centers of the dots in the case of negative DEP, and attracted to the dot edges in the case of positive DEP [25].

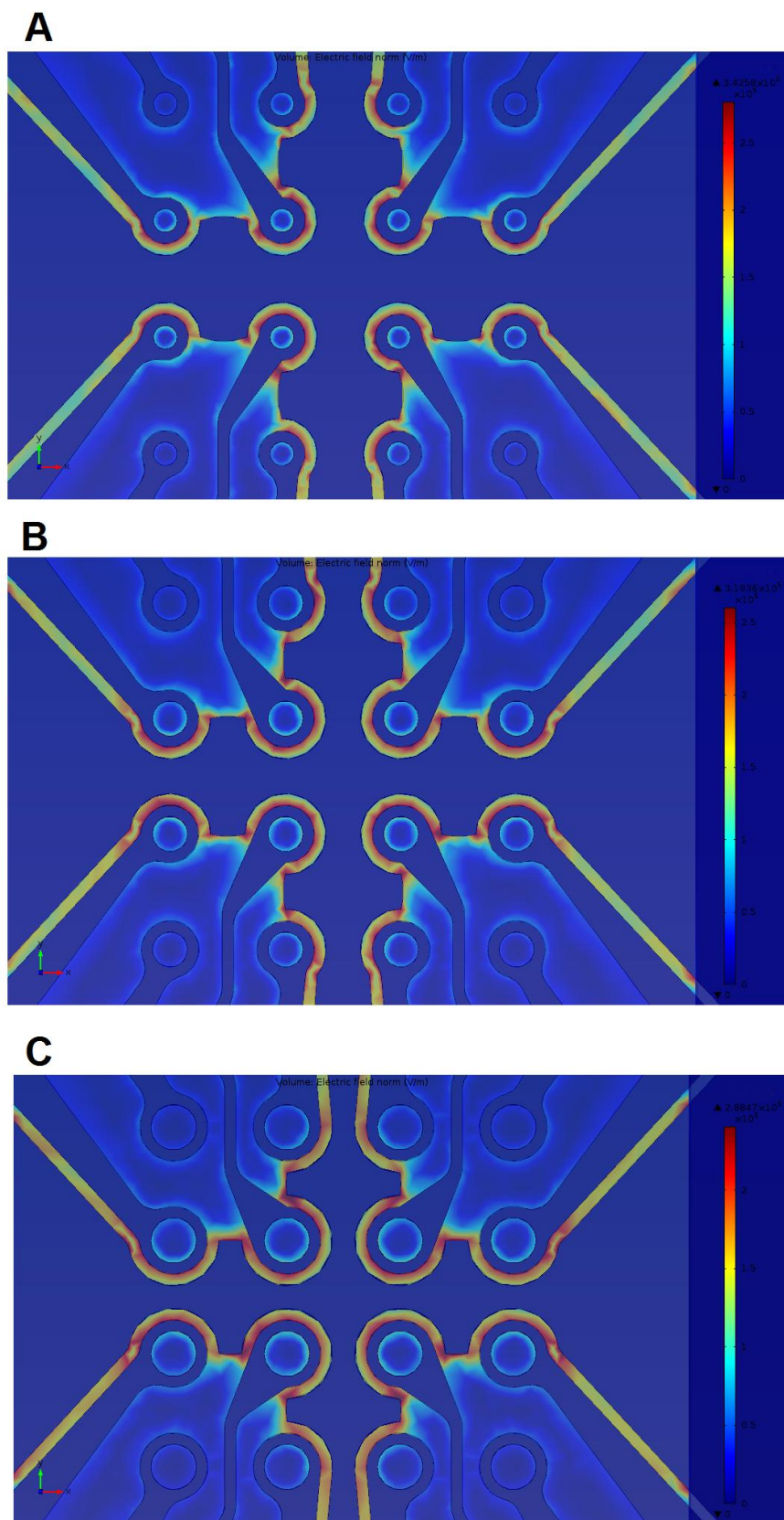
The maximum values of the electric field strengths for the two electrode designs are summarized in Table 1 for the prescribed dot diameters. Results confirm that the strength of the electric field increases when ground plane is introduced between the adjacent dots. According to Stulik

et al., the gaps between adjacent electrodes should be wide enough compared to the diffusion layer thickness; in order to prevent the overlapping between the diffusion layers of the adjacent electrodes [26]. Thus, the advantageous outcome of inserting ground plane between adjacent dots in the proposed electrode is due to the fact that the overlapping that might occur between the electric fields generated by adjacent dots is avoided; since the ground plane absorbs any charges in this area.



**Figure 2.** The electric field strengths of electrodes without ground plane between dots apertures, with dots diameters (A)100 μm, (B)150 μm and (C)200 μm. Dots diameters are adjusted by changing the ring width.

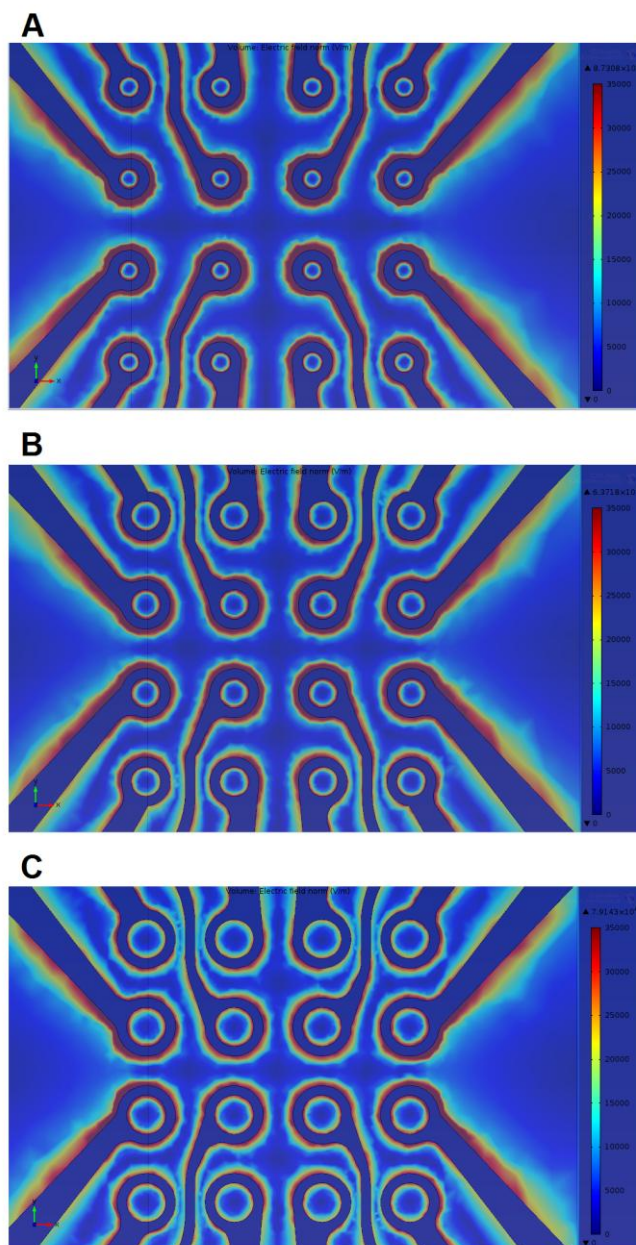




**Figure 3.** The electric field strengths of electrodes with ground plane between dots apertures, with dots diameters (A)100  $\mu\text{m}$ , (B)150  $\mu\text{m}$  and (C)200  $\mu\text{m}$ . Dots diameters are adjusted by changing the ring width.

**Table 1.** Maximum electric field strengths (V/m) of electrodes with/without ground plane between dot apertures for different dots diameters.

Dot Diameter (μm)	100	150	200
Electrodes without ground plane between dots	$7.057 \times 10^4$	$7.423 \times 10^4$	$7.914 \times 10^4$
Electrodes with ground plane between dots	$3.426 \times 10^5$	$3.194 \times 10^5$	$2.885 \times 10^5$



**Figure 4.** The electric field strengths of electrodes without ground plane between dots apertures, with dots diameters (A)100 μm, (B)150 μm and (C)200 μm. Dots diameters are adjusted by changing the distance between adjacent dots.



**Table 2.** Maximum electric field strengths (V/m) of electrodes without ground plane between dot apertures with fixed dots separation distance and with fixed ring width for different dots diameters.

Dot Diameter ( $\mu\text{m}$ )	100	150	200
Electrodes with fixed dots separation distance (150 $\mu\text{m}$ )	$7.057 \times 10^4$	$7.423 \times 10^4$	$7.914 \times 10^4$
Electrodes with fixed ring width (50 $\mu\text{m}$ )	$8.731 \times 10^4$	$6.372 \times 10^4$	$7.914 \times 10^4$

Table 1 shows that the values of electric field strength are decreased when the diameter of the dots in the electrodes are increased with ground plane between dots. The highest electric field strength value is  $3.426 \times 10^5$  V/m and this is associated with an electrode that has a dot diameter of 100  $\mu\text{m}$ .

On the other hand, the values of electric field strength are increased as the diameters of the dots in the electrodes are increased when there is no ground plane between dots, as shown in Table 1. The maximum electric field strength was produced by an electrode that had a dot diameter of 200  $\mu\text{m}$ .

Changing dot diameters in the previous electrodes was done by changing the ring width. To explore what effects the ring width may have on the electric field strength and distribution, electrodes with different dot diameters were designed with fixed ring width (50  $\mu\text{m}$ ) for all sizes of dots, while varying the distances between the adjacent dots. The results of the electric field strengths of these electrodes are shown in Fig. 4. The results reveal that the distribution of the electric field over the dot electrodes is similar to that shown in Fig. 2. Hence, ring width does not affect electric field distribution.

Table 2 depicts the maximum values of the electric field strengths of electrodes with fixed dots separation distance and electrodes with fixed rings. The findings show that there are insignificant differences between the two cases. Therefore, ring width has no major effect on the induced electric field strength over the dot electrodes.

#### 4. CONCLUSION

A numerical analysis of the induced electric field over multiple microarray dot electrodes was demonstrated and the electric field strength and distribution of the designed electrodes with different dot sizes were explored. The effect of adding ground plane between the apertures of the dots was evaluated. Results confirm that frequency has a negligible effect on the electric field generated by the microarray dot electrodes. Simulations have shown that the electric field is axisymmetrical around the center of the dot aperture, and that it is higher at the edges of the dots than it is at center of the dots. Furthermore, the results analysis confirms that the electric field strength increases when adding ground plane between adjacent dots.

## ACKNOWLEDGMENT

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